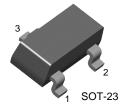


BCX70K

General Purpose Transistor



NPN Epitaxial Silicon Transistor

1. Base 2. Emitter 3. Collector

Absolute Maximum Ratings T_a=25°C unless otherwise noted

| Symbol | Parameter | Value | Units |
|------------------|-----------------------------|-----------|-------|
| V _{CBO} | Collector-Base Voltage | 45 | V |
| V _{CEO} | Collector-Emitter Voltage | 45 | V |
| V _{EBO} | Emitter-Base Voltage | 5 | V |
| I _C | Collector Current | 200 | mA |
| P _C | Collector Power Dissipation | 350 | mW |
| T _{STG} | Storage Temperature | -55 ~ 150 | °C |

Refer to KST3904 for graphs

Electrical Characteristics T_a=25°C unless otherwise noted

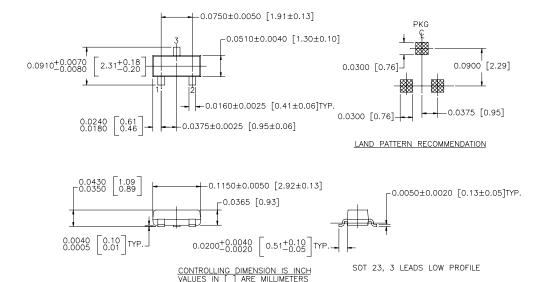
| Symbol | Parameter | Test Condition | Min. | Max. | Units |
|-----------------------|--------------------------------------|--|-------------------|--------------|--------|
| BV _{CEO} | Collector-Emitter Breakdown Voltage | I _C =2.0mA, I _B =0 | 45 | | V |
| BV _{EBO} | Emitter-Base Breakdown Voltage | I _E =1.0μA, I _C =0 | 5 | | V |
| I _{CES} | Collector Cut-off Current | V _{CE} =32V, V _{BE} =0 | | 20 | nA |
| I _{EBO} | Emitter Cut-off Current | V _{EB} =4V, I _C =0 | | 20 | nA |
| h _{FE} | DC Current Gain | V_{CE} =5V, I_{C} =10 μ A V_{CE} =5V, I_{C} =2.0mA V_{CE} =1V, I_{C} =50mA | 100 380 100 | 630 | |
| V _{CE} (sat) | Collector-Emitter Saturation Voltage | I _C =10mA, I _B =0.25mA I _C =50mA, I _B =1.25mA | | 0.35 0.55 | V V |
| V _{BE} (sat) | Base-Emitter Saturation Voltage | I _C =10mA, I _B =0.25mA I _C =50mA, I _B =1.25mA | 0.6 0.7 | 0.85 1.05 | V V |
| V _{BE} (on) | Base-Emitter On Voltage | I _C =2.0mA, V _{CE} =5V | 0.55 | 0.75 | V |
| f _T | Current Gain Bandwidth Product | I _C =10mA, V _{CE} =5V, f=100MHz | 125 | | MHz |
| C _{ob} | Output Capacitance | V _{CB} =10V, I _E =0, f=1MHz | | 4.5 | pF |
| NF | Noise Figure | V_{CE} =5V, I_{C} =0.2mA R_{S} =2K Ω , f=1KHz | | 6 | dB |
| t _{ON} | Turn On Time | I _C =10mA, I _{B1} =1.0mA | | 150 | ns |
| t _{OFF} | Turn Off Time | V_{BB} =3.6V, I_{B2} =1.0mA R_1 = R_2 =5K Ω , R_L =990 Ω | | 800 | ns |

Marking



Package Dimensions

SOT-23



NOTE: UNLESS OTHERWISE SPECIFIED

- 1. STANDARD LEAD FINISH 150 MICROINCHES / 3.81 MICROMETERS MINIMUM TIN / LEAD (SOLDER) ON ALLOY 42
- 2. REFERENCE JEDEC REGISTRATION TO-236, VARIATION AB, ISSUE G, DATED JUL 1993

Dimensions in Millimeters

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| EnSigna™ | I^2C^{TM} | OCX^{TM} | RapidConfigure™ | UHC™ |
| Across the board. | . Around the world.™ | OCXPro™ | RapidConnect™ | UltraFET [®] |
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|--------------------------|---------------------------|---|
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